SKiiP 03AC126V1

MiniSKiiP®0

3-phase bridge inverter
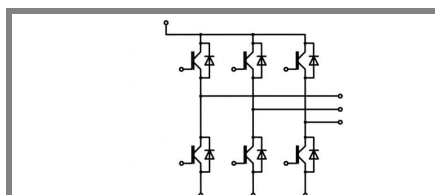
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Target Data

Features

- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Remarks

- V_{CEsat}, V_F = chip level value

Absolute Maximum Ratings		T_S = 25 °C, unless otherwise specified	
Symbol	**Conditions**	**Values**	**Units**
IGBT - Inverter			
V_{CES}		1200	V
I_C	T_s = 25 (70) °C	19 (15)	A
I_{CRM}	T_s = 25 (70) °C, $t_p \leq$ 1 ms	38 (30)	A
V_{GES}		± 20	V
T_j		-40...+150	°C
Diode - Inverter			
I_F	T_s = 25 (70) °C	14 (11)	A
I_{FRM}	T_s = 25 (70) °C, $t_p \leq$ 1 ms	28 (22)	A
T_j		-40...+150	°C
I_{tRMS}	per power terminal (20 A / spring)	20	A
T_{stg}	$T_{op} \leq T_{stg}$	-40...+125	°C
V_{isol}	AC, 1 min.	2500	V

Characteristics		T_S = 25 °C, unless otherwise specified			
Symbol	**Conditions**	**min.**	**typ.**	**max.**	**Units**
IGBT - Inverter					
V_{CEsat}	I_C = 8 A, T_j = 25 (125) °C		1,7 (2)	2,1 (2,4)	V
$V_{GE(th)}$	V_{GE} = V_{CE}, I_C = 0,3 mA	5	5,8	6,5	V
$V_{CE(TO)}$	T_j = 25 (125) °C		1 (0,9)	1,2 (1,1)	V
r_T	T_j = 25 (125) °C		87 (138)	113 (162)	mΩ
C_{ies}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		0,7		nF
C_{oes}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		0,1		nF
C_{res}	V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		0,1		nF
$R_{th(j-s)}$	per IGBT		1,5		K/W
$t_{d(on)}$	under following conditions		35		ns
t_r	V_{CC} = 600 V, V_{GE} = ± 15 V		25		ns
$t_{d(off)}$	I_C = 8 A, T_j = 125 °C		365		ns
t_f	R_{Gon} = R_{Goff} = 50 Ω		105		ns
E_{on}	inductive load		0,8		mJ
E_{off}			0,95		mJ
Diode - Inverter					
V_F = V_{EC}	I_F = 8 A, T_j = 25 (125) °C		1,9 (2)	2,2 (2,4)	V
$V_{(TO)}$	T_j = 25 (125) °C		1 (0,8)	1,1 (0,9)	V
r_T	T_j = 25 (125) °C		112 (150)	138 (187)	mΩ
$R_{th(j-s)}$	per diode		2,5		K/W
I_{RRM}	under following conditions		12		A
Q_{rr}	I_F = 8 A, V_R = 600 V		1,8		µC
E_{rr}	V_{GE} = 0 V, T_j = 125 °C		0,9		mJ
	di_F/dt = 520 A/µs				
Temperature Sensor					
R_{ts}	3 %, T_r = 25 (100) °C		1000(1670)		Ω
Mechanical Data					
m			21,5		g
M_s	Mounting torque	2		2,5	Nm

AC

circuit

⊙ power connector
∘ control connector

pinout, dimensions

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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